

2SD21780RA Datasheet

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DiGi Electronics Part Number	2SD21780RA-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SD21780RA
Description	TRANS NPN 50V 2A MT-3
Detailed Description	Bipolar (BJT) Transistor NPN 50 V 2 A 150MHz 1.5 W Through Hole MT-3-A1



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Purchase and inquiry

Manufacturer Product Number:

2SD21780RA

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

50 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

1.5 W

Operating Temperature:

150°C (TJ)

Package / Case:

3-SIP

Base Product Number:

2SD2178

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

2 A

Vce Saturation (Max) @ Ib, Ic:

300mV @ 50mA, 1A

DC Current Gain (hFE) (Min) @ Ic, Vce:

120 @ 200mA, 2V

Frequency - Transition:

150MHz

Mounting Type:

Through Hole

Supplier Device Package:

MT-3-A1

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.29.0075

ECCN:

EAR99

2SD2178

Silicon NPN epitaxial planar type

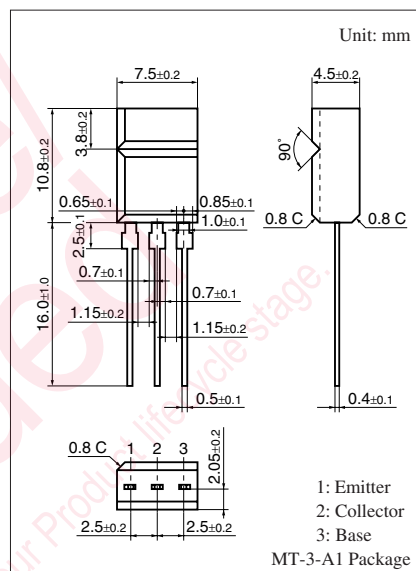
For low-frequency output amplification

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Large collector current I_C

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	50	V
Collector-emitter voltage (Base open)	V_{CEO}	50	V
Emitter-base voltage (Collector open)	V_{EBO}	5	V
Collector current	I_C	2	A
Peak collector current	I_{CP}	3	A
Collector power dissipation	P_C	1.5	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$



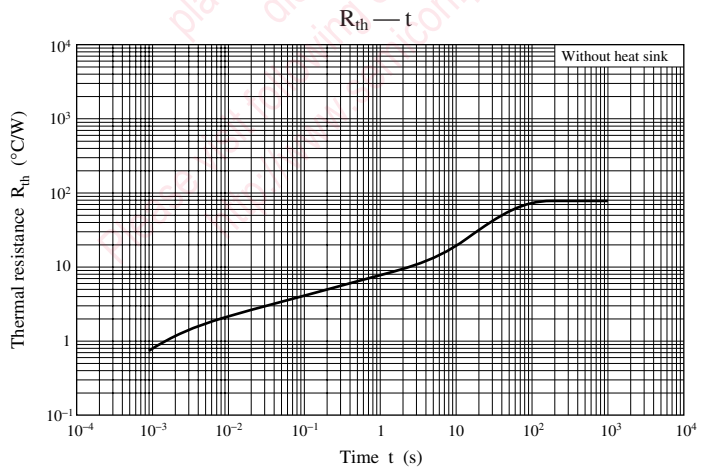
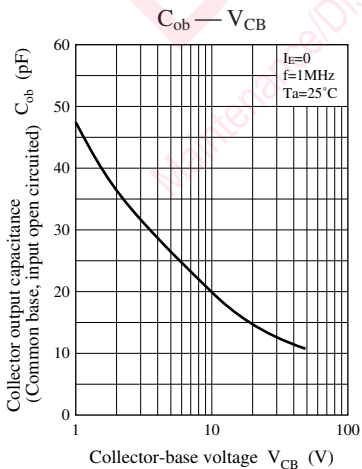
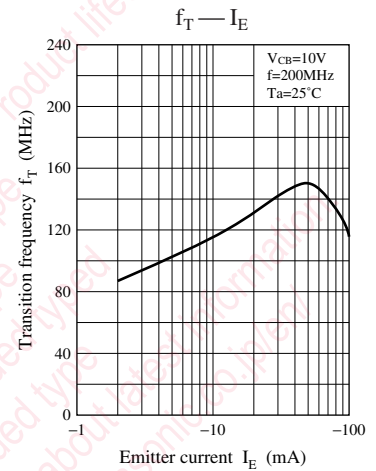
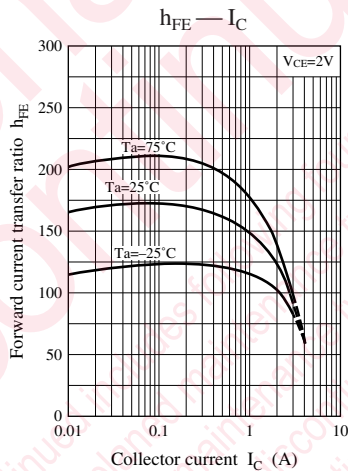
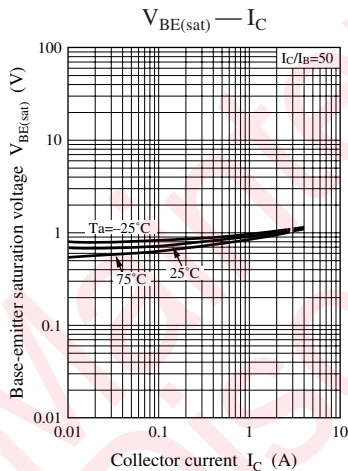
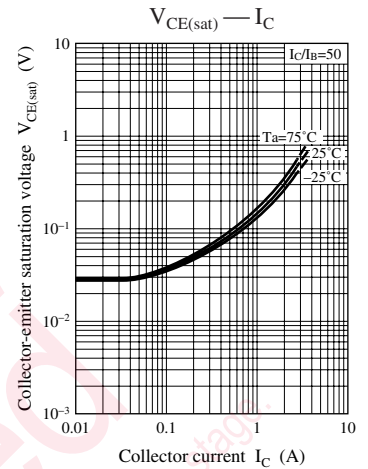
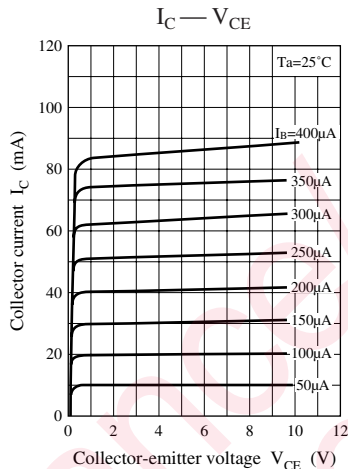
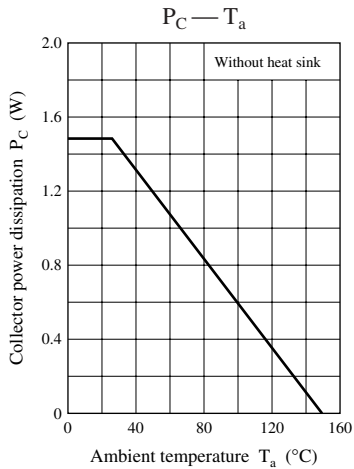
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	50			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μA
Forward current transfer ratio	h_{FE1}^*	$V_{CE} = 2 \text{ V}, I_C = 200 \text{ mA}$	120		340	—
	h_{FE2}	$V_{CE} = 2 \text{ V}, I_C = 1 \text{ A}$	80			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 1 \text{ A}, I_B = 50 \text{ mA}$		0.15	0.30	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 1 \text{ A}, I_B = 50 \text{ mA}$		0.9	1.2	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		23	35	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	R	S
h_{FE1}	120 to 240	170 to 340



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